NSN 5961-01-200-4075

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View Online at https://aerobasegroup.com/nsn/5961-01-200-4075

Inclosure Material: Metal **Overall Length:** 1.218 inches **End Application:** F-16 simulator; aircraft; spt equipment, mx peacekeeper; aircraft, a **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-59 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 58.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 7.0 small-signal short-circuit forward current transfer ratio, common-emitter **Special Features:** Weapon system essential; junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:**

Unf

Terminal Type And Quantity:

3 tab, solder lug

Specification Data:

91240 mil a 10500/525 gayarament apositioation

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0